

# CD54FCT245, CD74FCT245

## BiCMOS FCT Interface Logic, Octal-Bus Transceivers, Three-State

### Features

- Buffered Inputs
- Typical Propagation Delay: 5.0ns at  $V_{CC} = 5V$ ,  $T_A = 25^\circ C$
- Noninverting
- SCR Latchup Resistant BiCMOS Process and Circuit Design
- Speed of Bipolar FAST™/AS/S
- 64mA Output Sink Current (74 Series)
- 48mA Output Sink Current (54 Series)
- Output Voltage Swing Limited to 3.7V at  $V_{CC} = 5V$
- Controlled Output Edge Rates
- Input/Output Isolation to  $V_{CC}$
- BiCMOS Technology with Low Quiescent Power

### Description

The CD54/74FCT245 octal bus transceiver uses a small geometry BiCMOS technology. The output stage is a combination of bipolar and CMOS transistors that limits the output HIGH level to two diode drops below  $V_{CC}$ . This resultant lowering of output swing (0V to 3.7V) reduces power bus ringing (a source of EMI) and minimizes  $V_{CC}$  bounce and ground bounce and their effects during simultaneous output switching. The output configuration also enhances switching speed and is capable of sinking 48mA to 64mA.

The CD54/74FCT245 is a noninverting, three-state, bidirectional transceiver/buffer intended for two-way transmission from "A" bus to "B" bus or "B" bus to "A" bus. The logic level present on the Direction Input (DIR) determines the data direction. When the Output Enable input is HIGH, the outputs are in the high impedance state.

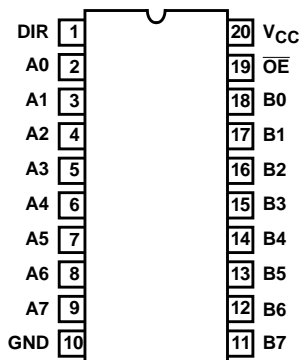
### Ordering Information

PART NUMBER	TEMP. RANGE ( $^\circ C$ )	PACKAGE	PKG. NO.
CD74FCT245E	0 to 70	20 Ld PDIP	E20.3
CD74FCT245M	0 to 70	20 Ld SOIC	M20.3
CD54FCT245E	-55 to 125	20 Ld PDIP	E20.3

NOTE: When ordering the suffix M and SM packages, use the entire part number. Add the suffix 96 to obtain the variant in the tape and reel.

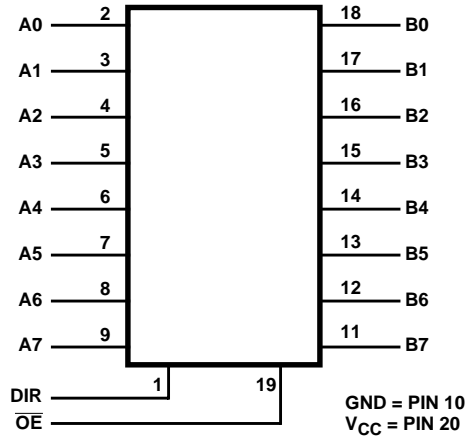
### Pinout

CD54FCT245, CD74FCT245  
(PDIP, SOIC)  
TOP VIEW



# CD54FCT245, CD74FCT245

## Functional Diagram



TRUTH TABLE (NOTE 1)

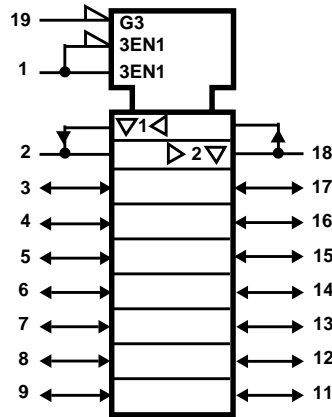
CONTROL INPUTS		OPERATION
OE	DIR	
L	L	B Data to A Bus
L	H	A Data to B Bus
H	X	Isolation

NOTES:

- 1. H = High Voltage Level  
L = Low Voltage Level  
X = Irrelevant
- 2. To prevent excess currents in the High-Z (isolation) modes, all I/O terminals should be terminated with 10kΩ to 1 MΩ resistors.

## IEC Logic Symbol

CD74FCT245, CD54FCT245



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## Absolute Maximum Ratings

DC Supply Voltage ( $V_{CC}$ )	-0.5V to 6.0V
DC Input Diode Current, $I_{IK}$ (for $V_I < -0.5V$ )	-20mA
DC Output Diode Current, $I_{OK}$ (for $V_O < -0.5V$ )	-50mA
DC Output Sink Current per Output Pin, $I_O$	70mA
DC Output Source Current per Output Pin, $I_O$	30mA
DC $V_{CC}$ Current ( $I_{CC}$ )	140mA
DC Ground Current ( $I_{GND}$ )	528mA

## Thermal Information

Thermal Resistance (Typical, Note 3)	$\theta_{JA}$ (°C/W)
PDIP Package	69
SOIC Package	58
Maximum Junction Temperature	150°C
Maximum Storage Temperature Range	-65°C to 150°C
Maximum Lead Temperature (Soldering 10s)	300°C (SOIC Lead Tips Only)

## Operating Conditions

Operating Temperature Range ( $T_A$ )	-55°C to 125°C
Supply Voltage Range, $V_{CC}$	
CD74 Series, $T_A = 0^\circ\text{C}$ to $70^\circ\text{C}$	4.75V to 5.25V
CD54 Series, $T_A = -55^\circ\text{C}$ to $125^\circ\text{C}$	4.5V to 5.5V
DC Input Voltage, $V_I$	0 to $V_{CC}$
DC Output Voltage, $V_O$	0 to $\leq V_{CC}$
Input Rise and Fall Slew Rate, $dt/dv$	0 to 10ns/V

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

NOTE:

- $\theta_{JA}$  is calculated in accordance with JESD 51.

**Electrical Specifications** 74FCT Commercial Temperature Range  $0^\circ\text{C}$  to  $70^\circ\text{C}$ ,  $V_{CC}$  Max = 5.25V,  $V_{CC}$  Min = 4.75V  
54FCT Extended Industrial Temperature Range  $-55^\circ\text{C}$  to  $125^\circ\text{C}$ ;  $V_{CC}$  Max = 5.5V,  $V_{CC}$  Min = 4.5V

PARAMETER	SYMBOL	TEST CONDITIONS		V <sub>CC</sub> (V)	AMBIENT TEMPERATURE (T <sub>A</sub> )						UNITS
					25°C		0°C TO 70°C		-55°C TO 125°C		
		V <sub>I</sub>	I <sub>O</sub> (mA)		MIN	MAX	MIN	MAX	MIN	MAX	
High Level Input Voltage	V <sub>IH</sub>			4.5 to 5.5	2	-	2	-	2	-	V
Low Level Input Voltage	V <sub>IL</sub>			4.5 to 5.5	-	0.8	-	0.8	-	0.8	V
High Level Output Voltage	V <sub>OH</sub>	V <sub>IH</sub> or V <sub>IL</sub>	-15	Min	2.4	-	2.4	-	-	-	V
			-12	Min	2.4	-	-	-	2.4	-	V
Low Level Output Voltage	V <sub>OL</sub>	V <sub>IH</sub> or V <sub>IL</sub>	64	Min	-	0.55	-	0.55	-	-	V
			48	Min	-	0.55	-	-	-	0.55	V
High Level Input Current	I <sub>IH</sub>	V <sub>CC</sub>		Max	-	0.1	-	1	-	1	μA
Low Level Input Current	I <sub>IL</sub>	GND		Max	-	-0.1	-	-1	-	-1	μA
Three-State Leakage Current	I <sub>OZH</sub>	V <sub>CC</sub>		Max	-	0.5	-	10	-	10	μA
	I <sub>OZL</sub>	GND		Max	-	-0.5	-	-10	-	-10	μA
Short Circuit Output Current (Note 4)	I <sub>OS</sub>	V <sub>CC</sub> or GND V <sub>O</sub> = 0		Max	-60	-	-60	-	-60	-	mA
Input Clamp Voltage	V <sub>IK</sub>	V <sub>CC</sub> or GND	-18	Min	-	-1.2	-	-1.2	-	-1.2	V
Quiescent Supply Current, MSI	I <sub>CC</sub>	V <sub>CC</sub> or GND	0	Max	-	8	-	80	-	500	μA
Additional Quiescent Supply Current per Input Pin TTL Inputs High, 1 Unit Load	ΔI <sub>CC</sub>	3.4V (Note 5)		Max	-	1.6	-	1.6	-	2	mA

NOTES:

- Not more than one output should be shorted at one time. Test duration should not exceed 100ms.
- Inputs that are not measured are at  $V_{CC}$  or GND.
- FCT Input Loading: All inputs are 1 unit load. Unit load is  $\Delta I_{CC}$  limit specified in Static Characteristics Chart, e.g., 1.6mA Max at  $70^\circ\text{C}$ .

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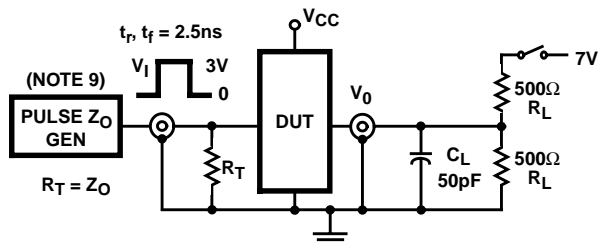
## Switching Specifications $t_r, t_f = 2.5\text{ns}$ , $C_L = 50\text{pF}$ , $R_L$ - See Figure 3

PARAMETER	SYMBOL	V <sub>CC</sub> (V)	AMBIENT TEMPERATURE (T <sub>A</sub> )							UNITS
			25°C	0°C TO 70°C			-55°C TO 125°C			
			TYP	MIN	TYP	MAX	MIN	TYP	MAX	
Propagation Delays Data to Outputs)	t <sub>PLH</sub> , t <sub>PHL</sub>	5	5	1.5	-	7	1.5	-	7.5	ns
Output Enable to Output	t <sub>PZL</sub> , t <sub>PZH</sub>	5	6	1.5	-	9.5	1.5	-	10	ns
Output Disable to Output	t <sub>PLZ</sub> , t <sub>PHZ</sub>	5	6	1.5	-	7.5	1.5	-	10	ns
Power Dissipation Capacitance	C <sub>PD</sub>	-	49	-	49	-	-	49	-	pF
Min (Valley) V <sub>OHV</sub> During Switching of Other Outputs (Output Under Test Not Switching)	V <sub>OHV</sub>	5	0.5	-	-	-	-	-	-	V
Max (Peak) V <sub>OLP</sub> During Switching of Other Outputs (Output Under Test Not Switching)	V <sub>OLP</sub>	5	1	-	-	-	-	-	-	V
Input Capacitance	C <sub>I</sub>	-	-	-	-	10	-	-	10	pF
Input/Output Capacitance	C <sub>I/O</sub>	-	-	-	-	15	-	-	15	pF

### NOTES:

7. 5V: Min is at 5.5V, Max is at 4.5V.  
5V: Min is at 5.25V for 0°C to 70°C, Max is at 4.75V for 0°C to 70°C, Typ is at 5V.
8.  $C_{PD}$ , measured per function, is used to determine the dynamic power consumption.  
 $P_D$  (per package) =  $V_{CC} I_{CC} + \sum (V_{CC}^2 f_i C_{PD} + V_O^2 f_O C_L + V_{CC} \Delta I_{CC} D)$  where:  
 $V_{CC}$  = supply voltage  
 $\Delta I_{CC}$  = flow through current x unit load  
 $C_L$  = output load capacitance  
 $D$  = duty cycle of input high  
 $f_O$  = output frequency  
 $f_i$  = input frequency

# Test Circuits and Waveforms



NOTE:

9. Pulse Generator for All Pulses: Rate  $\leq 1.0\text{MHz}$ ;  $Z_{OUT} \leq 50\Omega$ ;  
 $t_r, t_f \leq 2.5\text{ns}$ .

FIGURE 1. TEST CIRCUIT

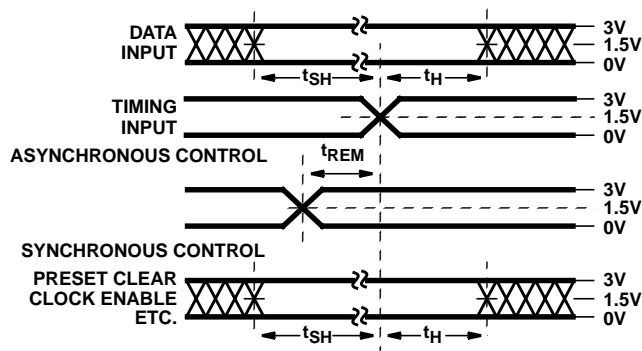


FIGURE 2. SETUP, HOLD, AND RELEASE TIMING

SWITCH POSITION	
TEST	SWITCH
$t_{PLZ}, t_{PZL}$ , Open Drain	Closed
$t_{PHZ}, t_{PZH}, t_{PLH}, t_{PHL}$	Open

DEFINITIONS:

$C_L$  = Load capacitance, includes jig and probe capacitance.

$R_T$  = Termination resistance, should be equal to  $Z_{OUT}$  of the Pulse Generator.

$V_{IN} = 0\text{V}$  to  $3\text{V}$ .

Input:  $t_r = t_f = 2.5\text{ns}$  (10% to 90%), unless otherwise specified

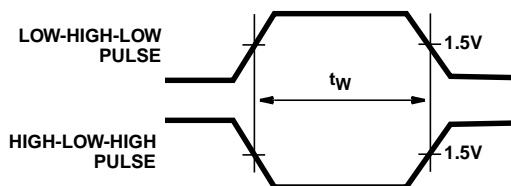


FIGURE 3. PULSE WIDTH

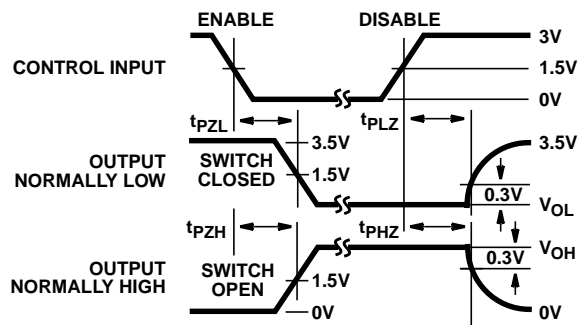


FIGURE 4. ENABLE AND DISABLE TIMING

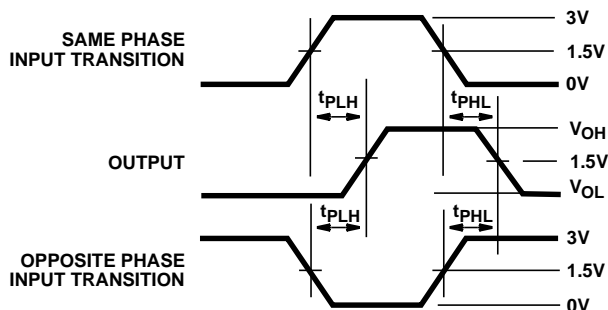
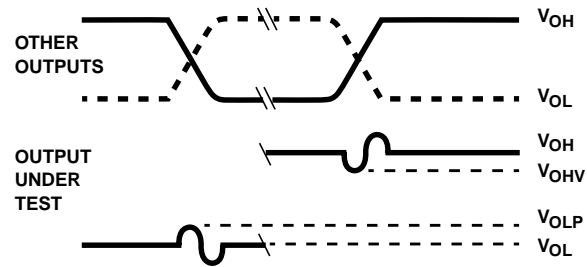


FIGURE 5. PROPAGATION DELAY

## Test Circuits and Waveforms (Continued)



### NOTES:

10.  $V_{OLP}$  is measured with respect to a ground reference near the output under test.  $V_{OHV}$  is measured with respect to  $V_{OH}$ .
11. Input pulses have the following characteristics:  
 $P_{RR} \leq 1\text{MHz}$ ,  $t_r = 2.5\text{ns}$ ,  $t_f = 2.5\text{ns}$ , skew 1ns.
12. R.F. fixture with 700MHz design rules required. IC should be soldered into test board and bypassed with 0.1 $\mu\text{F}$  capacitor. Scope and probes require 700MHz bandwidth.

**FIGURE 6. SIMULTANEOUS SWITCHING TRANSIENT WAVEFORMS**

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